## NSN 5962-01-328-5615

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View Online at https://aerobasegroup.com/nsn/5962-01-328-5615 **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.217 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and monolithic and programmed and erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 23 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.3 volts power source and 6.25 volts power source **Time Rating Per Chacteristic:** 350.00 nanoseconds propagation delay time, low to high level output and 350.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit

Demilitarization:

**Unit Of Measure:** 

Yes - demil/mli

Shelf Life:

N/a

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